

# Data Sheet

## HAL<sup>®</sup> 150y

Hall-Effect Switch with Open-Drain  
Output (3-wire) in SOT23 Package

**ASIL**|ready

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## Hall-Effect Switch with Open-Drain Output (3-wire) in SOT23 Package

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**Release Note: Revision bars indicate significant changes to the previous edition.**

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### 1. Introduction

The HAL 150y Hall-switch family members produced in CMOS technology as 3-wire device with open-drain output transistor include a temperature-compensated Hall plate with active offset compensation, a comparator, and an output stage.

The comparator compares the actual magnetic flux through the Hall plate (Hall voltage) with the fixed reference values (switching points). Accordingly the output transistor is switched on or off.

The active offset compensation leads to constant magnetic characteristics over supply voltage and temperature range. In addition, the magnetic parameters are robust against mechanical stress effects.

The sensor is designed for industrial and automotive applications and operates with supply voltages from 2.7 V to 24 V in the junction temperature range from  $-40\text{ }^{\circ}\text{C}$  up to  $170\text{ }^{\circ}\text{C}$ .

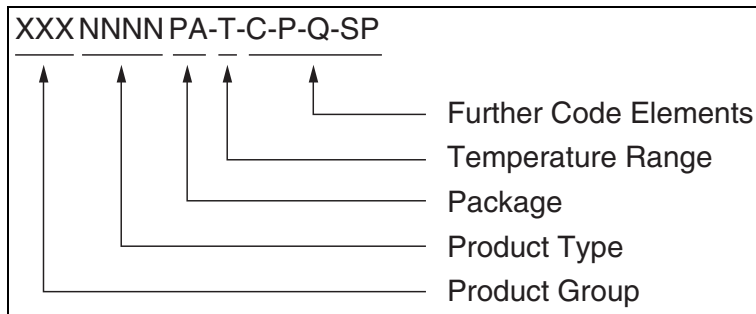
HAL 150y is available in a JEDEC TO236-compliant SMD-package 3-lead SOT23.

## 1.1. Features of HAL 150y

- SOT23-3L JEDEC TO236-compliant package
- ISO 26262 compliant as ASIL A ready device
- Short-circuit protected open-drain output and thermal shutdown
- Low current consumption of typ. 1.6 mA
- Operates with supply voltages from 2.7 V to 24 V
- Overvoltage protection capability up to 40 V
- Reverse-voltage protected VSUP-pin (–18 V)
- High ESD performance of  $\pm 8$  kV (HBM)
- Diagnostic features: power-on self test
- Sample frequency of 500 kHz, 2  $\mu$ s output refresh time
- Operates with static and dynamic magnetic fields up to 12 kHz
- High resistance to mechanical stress by active offset compensation
- Constant switching points over a wide supply voltage and temperature range
- Wide junction temperature range from –40 °C to 170 °C
- Built-in temperature coefficient
- Optimized for applications in extreme automotive and industrial environments
- Qualified according to AEC-Q100 test standard for automotive electronics industry to provide high-quality performance
- Robust EMC performance, corresponding to different standards, such as ISO 7637, ISO 16750, IEC 61967, ISO 11452, and ISO 62132

## 2. Ordering Information

A Micronas device is available in a variety of delivery forms. They are distinguished by a specific ordering code:



**Fig. 2–1:** Ordering Code Principle

For detailed information, please refer to the brochure: “Hall Sensors: Ordering Codes, Packaging, Handling”.

### 2.1. Device-Specific Ordering Codes

HAL 150y is available in the following package and temperature range.

**Table 2–1:** Available packages

Package Code (PA)	Package Type
SU	SOT23

**Table 2–2:** Available temperature ranges

Temperature Code (T)	Temperature Range
A	$T_J = -40\text{ °C to }+170\text{ °C}$

The relationship between ambient temperature ( $T_A$ ) and junction temperature ( $T_J$ ) is explained in **Section 5.2. on page 37**.

For available variants for Configuration (C), Packaging (P), Quantity (Q), and Special Procedure (SP) please contact Micronas.

**Table 2–3:** Available ordering codes and corresponding package marking

<b>Available Ordering Codes</b>	<b>Package Marking</b>
HAL1501SU-A-[C-P-Q-SP]	1501
HAL1502SU-A-[C-P-Q-SP]	1502
HAL1503SU-A-[C-P-Q-SP]	1503
HAL1506SU-A-[C-P-Q-SP]	1506
HAL1507SU-A-[C-P-Q-SP]	1507
HAL1508SU-A-[C-P-Q-SP]	1508
HAL1509SU-A-[C-P-Q-SP]	1509

### 3. Functional Description of HAL 150y

The HAL 150y sensors are monolithic integrated circuits which switch in response to magnetic fields. If a magnetic field with flux lines perpendicular to the sensitive area is applied to the sensor, the biased Hall plate forces a Hall voltage proportional to this field. The Hall voltage is compared with the actual threshold level in the comparator. If the magnetic field exceeds the threshold levels, the output stage is switched to the appropriate state.

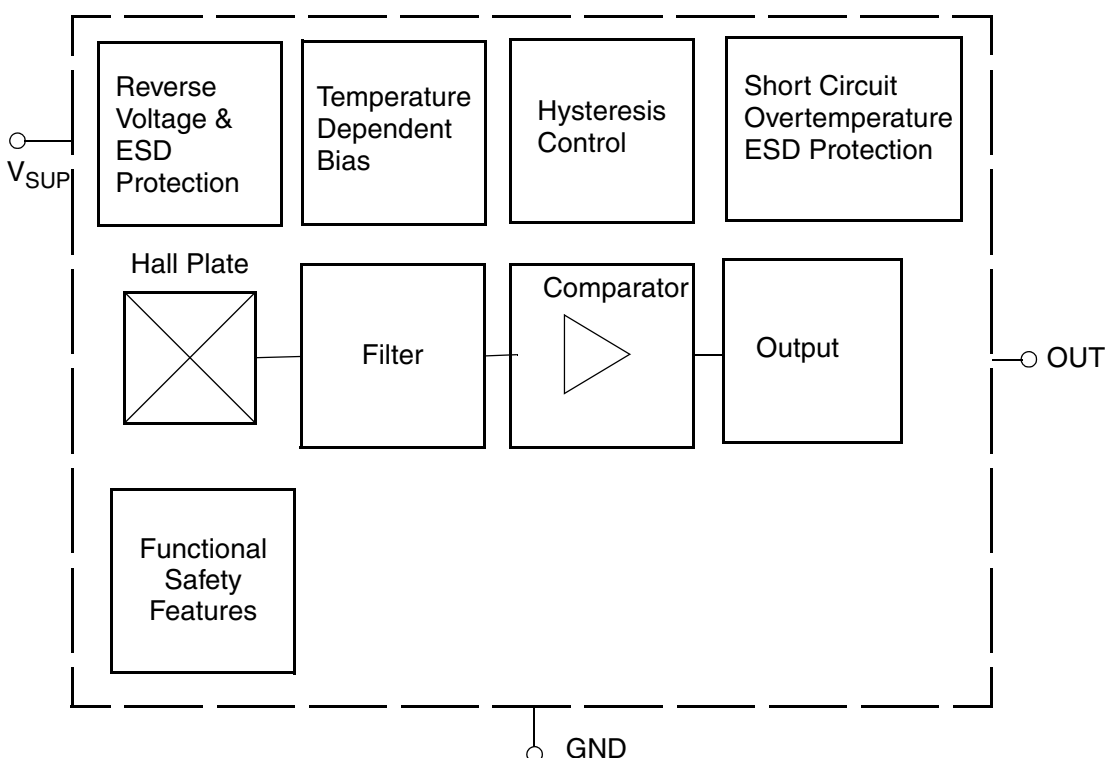
The built-in hysteresis eliminates oscillation and provides switching behavior of the output without bouncing.

Offsets caused by mechanical stress are compensated by using the “switching offset compensation technique”.

A diode on the supply line is not required thanks to the built-in reverse voltage protection.

The open drain output is forced to a safe, High-Z (high-impedance) state, in any of the following fault conditions: overtemperature, undervoltage and functional safety related diagnoses (see Section 3.1.). In addition, the output current is limited (short-circuit protection).

The device is able to withstand a maximum supply voltage of 24 V for unlimited time and features overvoltage capability (40 V load dump).



**Fig. 3–1:** HAL 150y block diagram



### 3.1. Functional Safety According to ISO 26262

The HAL 150y is ISO 26262 compliant as an ASIL A ready device.

Magnetic and switching performance is defined as a hardware safety requirement.

The safe state is defined as High-Z output.

#### 3.1.1. Diagnostic Features

Internal states are monitored and in an error condition flagged with a High-Z at the output:

- Internal voltage regulator: under and over voltage detection
- Monitoring of internal bias and current levels
- Monitoring of the internal reference voltage
- Monitoring of the Hall plate voltage

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**Note** For further documentation regarding functional safety please contact Micronas.

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### 3.2. Power-On Self-Test

The power-on self-test allows the customer to execute a functional check of the device, as well as to detect wire breaks as long as the host controls the power supply of the device.

The self-test can be enabled only once after power-on.

In order to start the test, the host has to power off the sensor and to pull down its output pin. Afterwards, the host needs to power on the sensor again (sensor in High-Z mode, after waking up) and then to release its output pin. This order of events is the criteria for the sensor to start the power-on self-test.

After releasing the output pin, the sensor simulates a magnetic field for a pre-defined period of time (see first observation window in Fig. 3–2), driving the sensor's output to low level, detected by the host.

Subsequently, the sensor simulates an opposite magnetic field during the second observation window (see Fig. 3–2), driving the sensor's output to high level, also detected by the host. The described self-test behavior is not impacted by external magnetic fields up to about 300 mT.

After self-test completion, the sensor always returns to normal operation regardless of the test result.

By positioning the pull-up resistor close to the control unit, wire breaks at all pins VSUP, OUT, and GND can be detected.

It is also possible to enable the power-on self-test in application systems, consisting of several HAL 150y sensors, as long, as the output pins are not connected to each other.

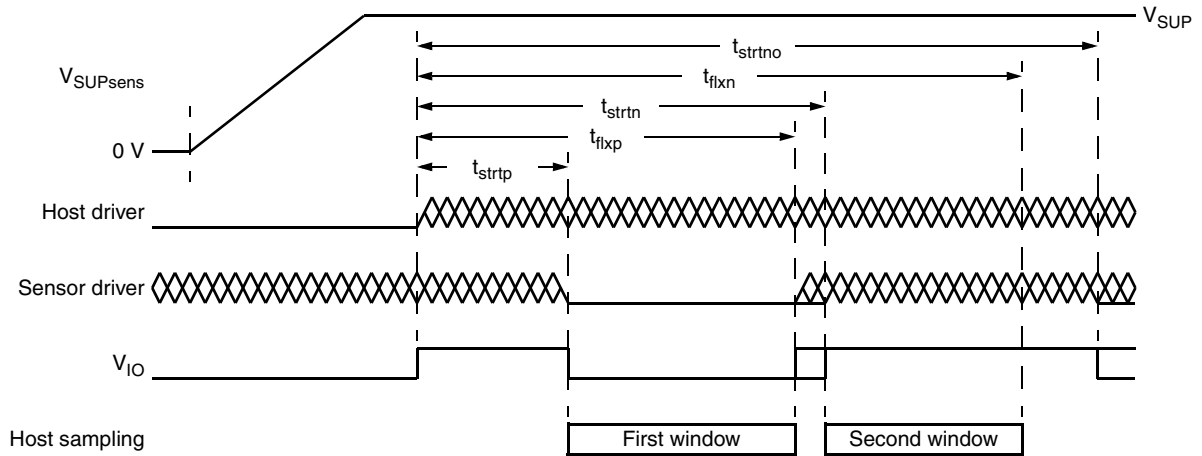


Fig. 3-2: Self-test timing diagram

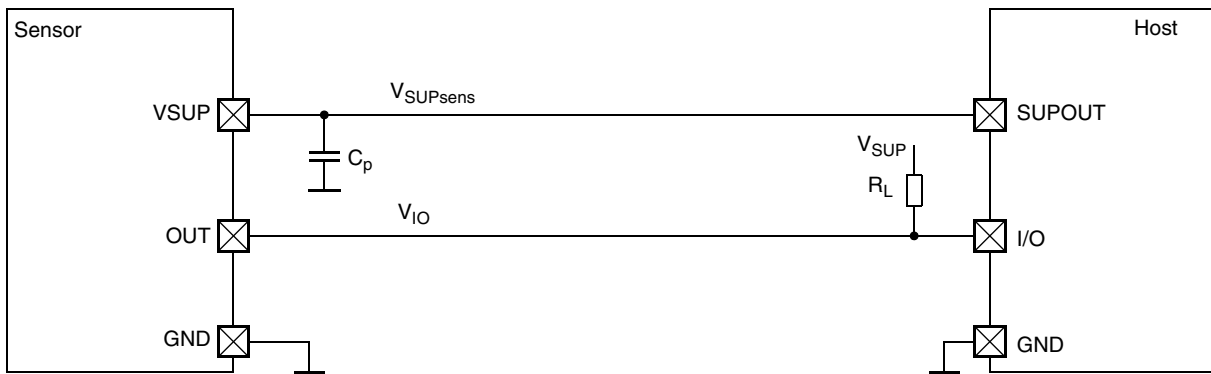
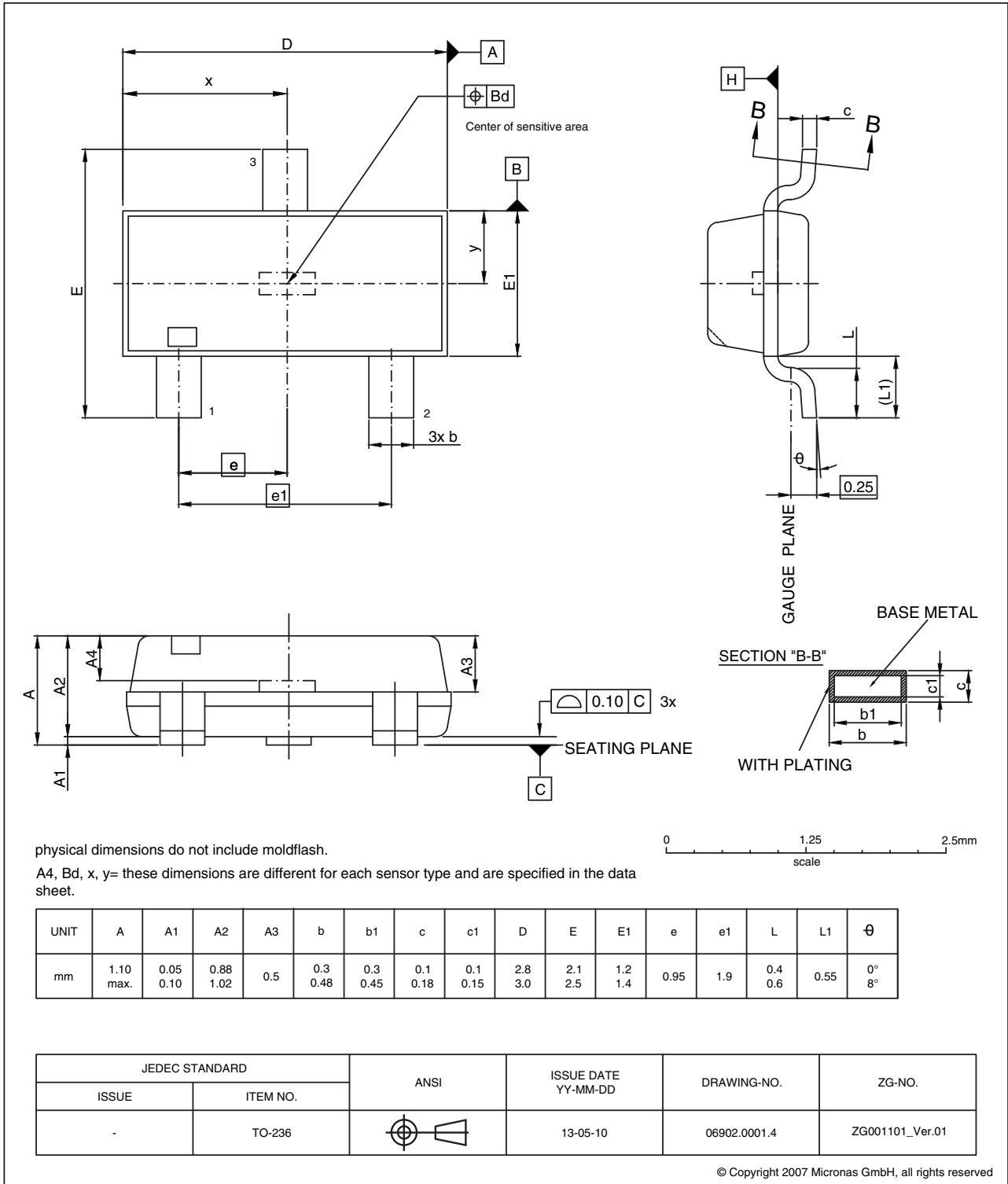


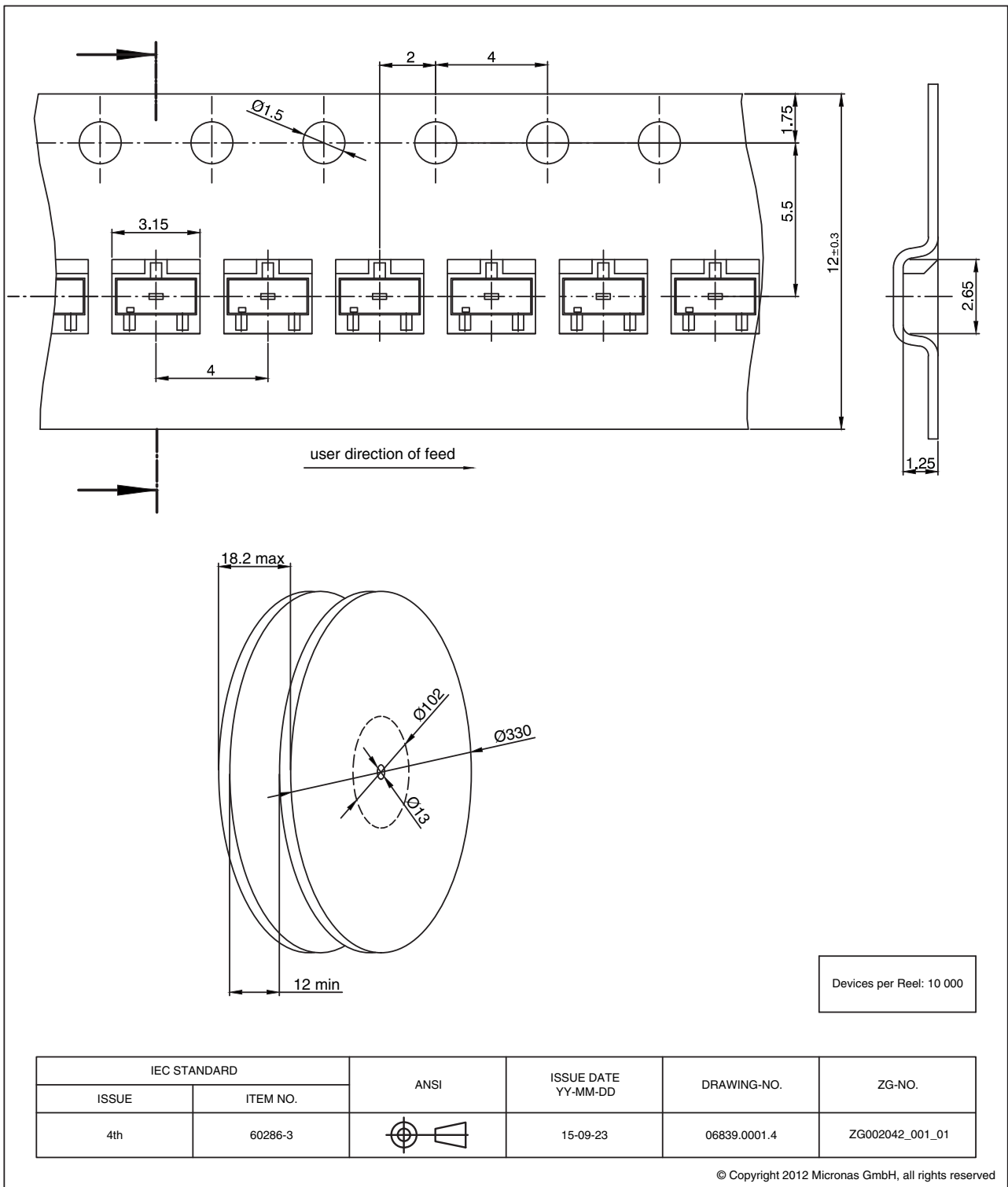
Fig. 3-3: External circuit diagram with switchable supply

## 4. Specifications

### 4.1. Outline Dimensions



**Fig. 4-1:**  
**SOT23: Plastic Small Outline Transistor package, 3 leads**  
 Ordering code: SU  
 Weight approximately 0.01094 g



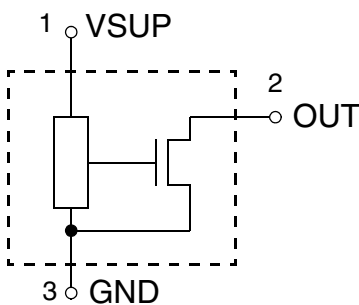
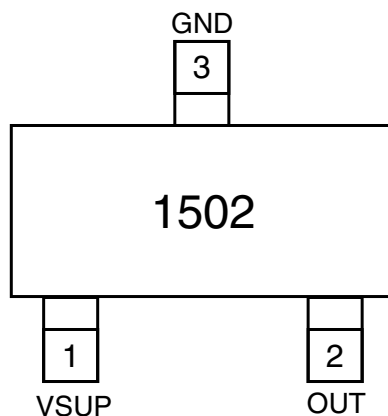
**Fig. 4-2:**  
**SOT23: Tape & Reel Finishing**

## 4.2. Soldering, Welding and Assembly

Information related to solderability, welding, assembly, and second-level packaging is included in the document “Guidelines for the Assembly of Micronas Packages”.

It is available on the Micronas website (<http://www.micronas.com/en/service-center/downloads>) or on the service portal (<http://service.micronas.com>).

## 4.3. Pin Connections (from Top Side, example HAL 1502) and Short Descriptions



**Fig. 4–3:** Pin configuration

**Table 4–1:** Pin assignment.

Pin number	Name	Function
1	VSUP	Supply voltage
2	OUT	Output
3	GND	Ground

#### 4.3.1. Dimension and Position of Sensitive Area

Parameter	Min.	Typ.	Max.	Unit
Dimension of sensitive area	–	100 x 100	–	$\mu\text{m}^2$
A4 (denotes the distance of die to top package surface in Z-direction)	0.24	0.27	0.37	mm
x (denotes the nominal distance of the center of the Bd circle to the package border in x-direction)	1.45			mm
y (denotes the nominal distance of the center of the Bd circle to the package border in y-direction)	0.65			mm
Bd (denotes the diameter of the circuit in which the center of the sensitive area is located)	–	–	0.23	mm

#### 4.4. Absolute Maximum Ratings

Stresses beyond those listed in the “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress rating only. Functional operation of the device at these conditions is not implied. Exposure to absolute maximum rating conditions for extended periods will affect device reliability.

This device contains circuitry to protect the inputs and outputs against damage due to high static voltages or electric fields; however, it is advised that normal precautions be taken to avoid application of any voltage higher than absolute maximum-rated voltages to this circuit.

All voltages listed are referenced to ground (GND).

Symbol	Parameter	Pin No	Min.	Max.	Unit	Conditions
$T_J$	Junction temperature range A	–	–40	190	°C	$t < 96 \text{ h}^{1)}$
$V_{SUP}$	Supply voltage	1	–18	28	V	$t < 96 \text{ h}^{1)}$
			–	32	V	$t < 5 \text{ min}^{1)}$
			–	40	V	$t < 10 \times 400 \text{ ms}$ “Load-Dump” <sup>1)</sup> with series resistor $R_V > 100 \Omega$
$V_{OUT}$	Output voltage	2	–0.5	28	V	$t < 96 \text{ h}^{1)}$
$I_O$	Output current	2	–	65	mA	
$I_{OR}$	Reverse output current	2	–50		mA	
1) No cumulative stress						



## 4.5. ESD and Latch-up

The output pin has to be in High-Z for ESD measurements.

**Table 4–2:** ESD and latch-up

Symbol	Parameter	Min.	Max.	Unit
$I_{\text{latch}}$	Maximum latch-up free current at any pin (measurement according to AEC Q100-004), class 1	–100	100	mA
$V_{\text{HBM}}$	Human body model (according to AEC Q100-002)	–8	8	kV
$V_{\text{CDM}}$	Charged device model (according to AEC Q100-011)	–1	1	kV
$V_{\text{SYSTEM\_LEVEL}}$	Unpowered Gun Test (150 pF / 330 $\Omega$ or 330 pF / 2 k $\Omega$ ) according to ISO 10605-2008 <sup>1)</sup>	–15	15	kV

<sup>1)</sup>only valid with ESD System Level Application Circuit (see Fig. 5–2 on page 34)

## 4.6. Storage and Shelf Life

Information related to storage conditions of Micronas sensors is included in the document “Guidelines for the Assembly of Micronas Packages”. It gives recommendations linked to moisture sensitivity level and long-term storage. It is available on the Micronas website (<http://www.micronas.com/en/service-center/downloads>) or on the service portal (<http://service.micronas.com>).

## 4.7. Recommended Operating Conditions

Functional operation of the device beyond those indicated in the “Recommended Operating Conditions” of this specification is not implied, may result in unpredictable behavior of the device, and may reduce reliability and lifetime.

All voltages listed are referenced to ground (GND).

Symbol	Parameter	Pin No	Min.	Typ.	Max.	Unit	Conditions
$V_{SUP}$	Supply voltage	1	2.7		24	V	
$\Delta V_{SUP} / \Delta t$	Power-down slope <sup>1)</sup>	1	–	–	0.1	V/ $\mu$ s	$V_{SUP}$ below 2.7 V
$T_J$	Junction temperature range A <sup>2)</sup>	–	–40		170 150 125	°C	t < 1000 h <sup>3)</sup> t < 2500 h <sup>3)</sup> t < 8000 h <sup>3)</sup>
$V_{OUT}$	Output voltage	2			24	V	
$I_{OUT}$	Output current	2			25	mA	
<p><sup>1)</sup> This parameter is relevant for ISO26262 applications: In order to ensure the defined output state (High-Z) during power-up in the range below the recommended supply voltage, the preceding power down slope is required to be slower than the maximum <math>\Delta V_{SUP} / \Delta t</math> value.</p> <p><sup>2)</sup> Depends on the temperature profile of the application. Please contact Micronas for life time calculations.</p> <p><sup>3)</sup> No cumulative stress</p>							

## 4.8. Characteristics

at  $T_J = -40\text{ °C}$  to  $+170\text{ °C}$ ,  $V_{SUP} = 2.7\text{ V}$  to  $24\text{ V}$ ,  
 at Recommended Operating Conditions if not otherwise specified in the column “Conditions”.  
 Typical Characteristics for  $T_J = 25\text{ °C}$  and  $V_{SUP} = 12\text{ V}$

Symbol	Parameter	Pin No.	Min.	Typ.	Max.	Unit	Conditions
Supply							
$I_{SUP}$	Supply current	1	1.1	1.6	2.4	mA	
$I_{SUPR}$	Reverse current	1	-1		-	mA	for $V_{SUP} = -18\text{ V}$
Port Output							
$V_{ol}$	Port low output voltage	2		0.13	0.4	V	$I_O = 20\text{ mA}$
					0.5	V	$I_O = 25\text{ mA}$
$I_{leak}$	Output leakage current			0.1	10	$\mu\text{A}$	
$t_f$	Output fall time <sup>1)</sup>	-			1	$\mu\text{s}$	$V_{SUP} = 12\text{ V}$ ; $R_L = 820\ \Omega$ ; $C_L = 20\text{ pF}$
$t_r$	Output rise time <sup>1)</sup>	-			1	$\mu\text{s}$	
$B_{noise}$	Effective noise of magnetic switching points (RMS) <sup>2)</sup>	-		72		$\mu\text{T}$	For square wave signal with 12 kHz
$t_j$	Output jitter (RMS) <sup>1)</sup>	-		$\pm 0.58$	$\pm 0.72$	$\mu\text{s}$	For square wave signal with 1 kHz. Jitter is evenly distributed between $-1\ \mu\text{s}$ and $+1\ \mu\text{s}$
$t_d$	Delay time <sup>2) 3)</sup>	-		16	21	$\mu\text{s}$	
$t_{samp}$	Output refresh period <sup>2)</sup>	-	1.6	2.2	3.0	$\mu\text{s}$	
$t_{en}$	Enable time of output after settling of $V_{SUP}$ <sup>4)</sup>	-		50	60	$\mu\text{s}$	$V_{SUP} = 12\text{ V}$ $B > B_{on} + 2\text{ mT}$ or $B < B_{off} - 2\text{ mT}$
<sup>1)</sup> Not tested, characterized only <sup>2)</sup> Guaranteed by design <sup>3)</sup> Systematic delay between magnetic threshold reached and output switching <sup>4)</sup> If power-on self-test is executed, $t_{en}$ will be extended by power-on self-test period (see Section )							

Symbol	Parameter	Pin No.	Min.	Typ.	Max.	Unit	Conditions
<b>Power-on Self-Test</b>							
$t_{dsamp}$	Double sample period <sup>2)</sup>	–	3.2	4.4	6.0	$\mu s$	
$t_{strtp}$	Start of first sampling window <sup>2)</sup>	–	–	–	4	$t_{dsamp}$	
$t_{flxp}$	End of first sampling window <sup>2)</sup>	–	9	–	–	$t_{dsamp}$	
$t_{strtn}$	Start of second sampling window <sup>2)</sup>	–	–	–	10	$t_{dsamp}$	
$t_{flxn}$	End of second sampling window <sup>2)</sup>	–	31	–	–	$t_{dsamp}$	
$t_{strtno}$	Start of first normal operation value <sup>2)</sup>	–	–	36.5	37	$t_{dsamp}$	
<b>Package</b>							
$R_{thja}$	Thermal Resistance junction to air	–	–	–	300	K/W	Measured with a 1s0p board
		–	–	–	250	K/W	Measured with a 1s1p board
		–	–	–	210	K/W	Measured with a 2s2p board
$R_{thjc}$	Thermal Resistance junction to case	–	–	–	30	K/W	Measured with a 1s0p board
		–	–	–	50	K/W	Measured with a 1s1p board
		–	–	–	40	K/W	Measured with a 2s2p board
<sup>2)</sup> Guaranteed by design							

## 4.9. HAL 1501 Magnetic Characteristics

The HAL 1501 bipolar Hall-switch provides highest sensitivity (see Fig. 4–4 on page 21).

The output turns low with the magnetic south pole on the top side of the package and turns high with the magnetic north pole on the top side. The output state is not defined if the magnetic field is removed again.

For correct functioning in the application, the sensor requires both magnetic polarities (north and south) on the top side of the package.

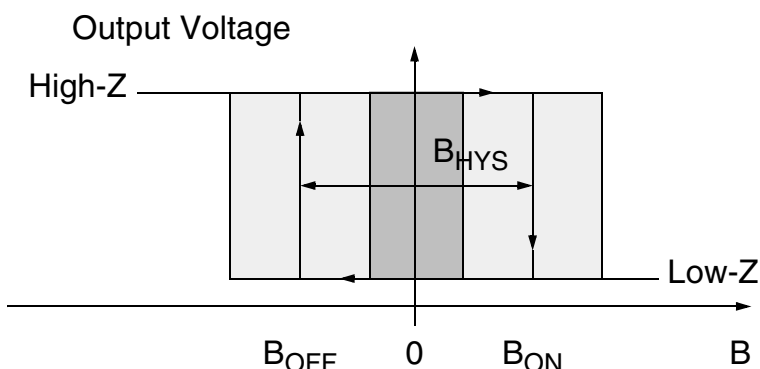
### Magnetic Features:

- switching type: bipolar
- very high sensitivity
- typical  $B_{ON}$ : 0.4 mT at room temperature
- typical  $B_{OFF}$ : –0.4 mT at room temperature
- operates with static magnetic fields and dynamic magnetic fields up to 12 kHz
- typical temperature coefficient of magnetic switching points is 0 ppm/K at room temperature

### Applications

The HAL 1501 is the optimal sensor for all applications with alternating magnetic signals and weak magnetic amplitude at the sensor position such as:

- applications with large air gap or weak magnets
- revolutions per minute (RPM) or other counting measurement, e.g. window lifter and sunroof
- commutation of brushless DC motors
- position detection, such as for gear-shift lever and electric parking brake
- magnetic encoders



**Fig. 4–4:** Definition of magnetic switching points for the HAL 1501

**Magnetic Characteristics** at  $T_J = -40\text{ °C}$  to  $+170\text{ °C}$ ,  $V_{DD} = 2.7\text{ V}$  to  $24\text{ V}$ ,  
 Typical Characteristics for  $V_{DD} = 12\text{ V}$

Magnetic flux density values of switching points:

Positive flux density values refer to the magnetic south pole at the top side of the package.

Parameter $T_J$	On point $B_{ON}$			Off point $B_{OFF}$			Hysteresis $B_{HYS}$			Unit
	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	
$-40\text{ °C}$	-0.6	0.5	1.6	-1.6	-0.5	0.6	–	1.0	–	mT
$25\text{ °C}$	-0.5	0.4	1.5	-1.5	-0.4	0.5	–	0.8	–	mT
$170\text{ °C}$	-1	0.35	2	-2	-0.35	1	–	0.7	–	mT

The hysteresis is the difference between the switching points |  $B_{HYS} = B_{ON} - B_{OFF}$  |

**Note** Regarding switching points, temperature coefficients, and B-field switching frequency, customized derivatives via mask option are possible. For more information contact Micronas.

## 4.10.HAL 1502 Magnetic Characteristics

The HAL 1502 Hall-latch provides highest sensitivity (see Fig. 4–5 on page 24).

The output turns low with the magnetic south pole on the top side of the package and turns high with the magnetic north pole on the top side. The output does not change if the magnetic field is removed. For changing the output state, the opposite magnetic field polarity must be applied.

For correct functioning in the application, the sensor requires both magnetic polarities (north and south) on the top side of the package.

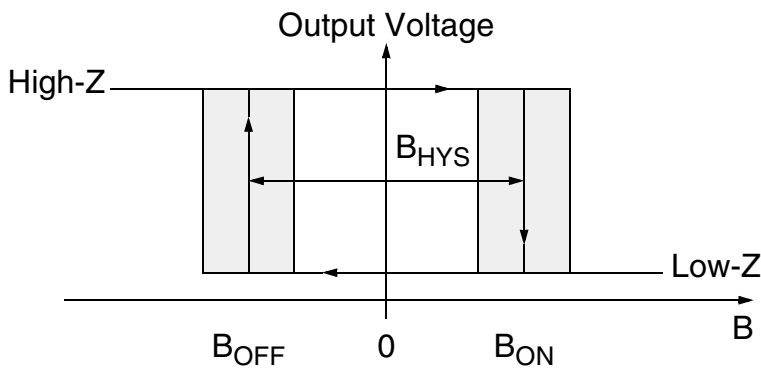
### Magnetic Features:

- switching type: latching
- high sensitivity
- typical  $B_{ON}$ : 2.5 mT at room temperature
- typical  $B_{OFF}$ : –2.5 mT at room temperature
- operates with static magnetic fields and dynamic magnetic fields up to 12 kHz
- typical temperature coefficient of magnetic switching points is –1000 ppm/K at room temperature

### Applications

The HAL 1502 is the optimal sensor for all applications with alternating magnetic signals and weak magnetic amplitude at the sensor position such as:

- applications with large air gap or weak magnets
- revolutions per minute (RPM) or other counting measurement, e.g. window lifter and sunroof
- commutation of brushless DC motors
- position detection, such as for adaptive front lighting and electric parking brake
- magnetic encoders



**Fig. 4–5:** Definition of magnetic switching points for the HAL 1502

**Magnetic Characteristics** at  $T_J = -40\text{ °C}$  to  $+170\text{ °C}$ ,  $V_{DD} = 2.7\text{ V}$  to  $24\text{ V}$ ,  
 Typical Characteristics for  $V_{DD} = 12\text{ V}$

Magnetic flux density values of switching points:

Positive flux density values refer to the magnetic south pole at the top side of the package.

Parameter $T_J$	On point $B_{ON}$			Off point $B_{OFF}$			Hysteresis $B_{HYS}$			Unit
	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	
-40 °C	1.3	2.8	4.3	-4.3	-2.8	-1.3	–	5.6	–	mT
25 °C	1	2.5	4	-4	-2.5	-1	–	5	–	mT
170 °C	0.8	2.3	3.8	-3.8	-2.3	-0.8	–	4.6	–	mT

The hysteresis is the difference between the switching points |  $B_{HYS} = B_{ON} - B_{OFF}$  |

**Note** Regarding switching points, temperature coefficients, and B-field switching frequency, customized derivatives via mask option are possible. For more information contact Micronas.



## 4.11.HAL 1503 Magnetic Characteristics

The HAL 1503 unipolar Hall-switch provides high sensitivity (see Fig. 4–6 on page 25).

The output turns low with the magnetic south pole on the top side of the package and turns high if the magnetic field is removed. The sensor does not respond to the magnetic north pole on the top side of the package.

For correct functioning in the application, the sensor requires only the magnetic south pole on the top side of the package.

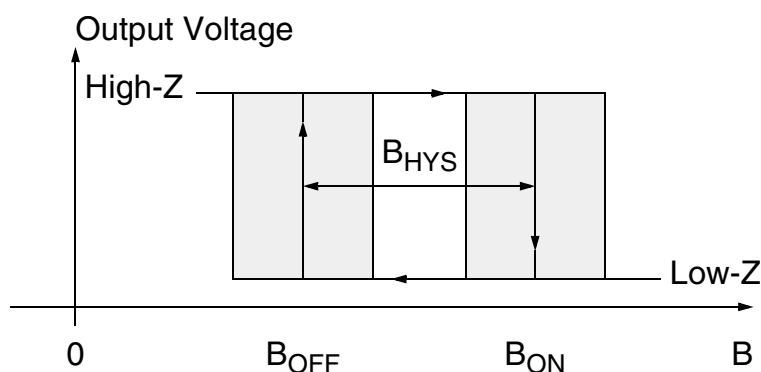
### Magnetic Features:

- switching type: unipolar
- high sensitivity
- typical  $B_{ON}$ : 5.5 mT at room temperature
- typical  $B_{OFF}$ : 3.7 mT at room temperature
- operates with static magnetic fields and dynamic magnetic fields up to 12 kHz
- typical temperature coefficient of magnetic switching points is  $-1000$  ppm/K at room temperature

### Applications

The HAL 1503 is the optimal sensor for all applications with one magnetic polarity and weak magnetic amplitude at the sensor position, such as:

- clutch position detection
- electric parking brake
- brake light switch
- brake pedal position detection
- steering wheel lock
- door handle



**Fig. 4–6:** Definition of magnetic switching points for the HAL 1503

**Magnetic Characteristics** at  $T_J = -40\text{ °C}$  to  $+170\text{ °C}$ ,  $V_{DD} = 2.7\text{ V}$  to  $24\text{ V}$ ,  
 Typical Characteristics for  $V_{DD} = 12\text{ V}$

Magnetic flux density values of switching points:

Positive flux density values refer to the magnetic south pole at the top side of the package.

Parameter $T_J$	On point $B_{ON}$			Off point $B_{OFF}$			Hysteresis $B_{HYS}$			Unit
	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	
$-40\text{ °C}$	4.4	6.1	7.6	2.4	4	5.7	–	2.1	–	mT
$25\text{ °C}$	3.8	5.5	7.1	2.1	3.7	5.5	–	1.8	–	mT
$170\text{ °C}$	3	5	6.7	1.8	3.6	5.5	–	1.4	–	mT

The hysteresis is the difference between the switching points |  $B_{HYS} = B_{ON} - B_{OFF}$  |

**Note** Regarding switching points, temperature coefficients, and B-field switching frequency, customized derivatives via mask option are possible. For more information contact Micronas.

## 4.12.HAL 1506 Magnetic Characteristics

The HAL 1506 unipolar Hall-switch provides medium sensitivity (see Fig. 4–7 on page 27).

The output turns low with the magnetic south pole on the top side of the package and turns high if the magnetic field is removed. The sensor does not respond to the magnetic north pole on the top side of the package.

For correct functioning in the application, the sensor requires only the magnetic south pole on the top side of the package.

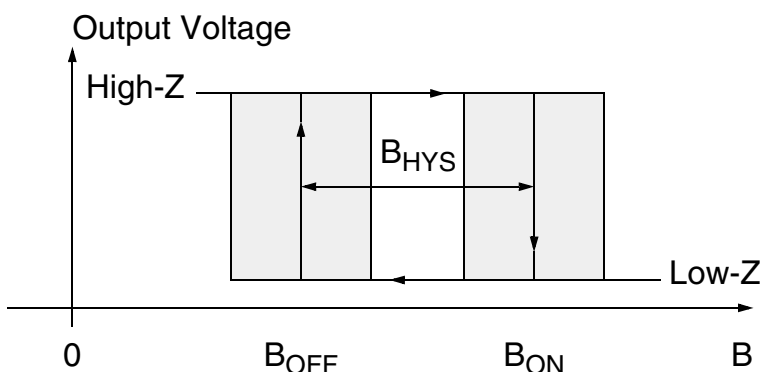
### Magnetic Features:

- switching type: unipolar
- medium sensitivity
- typical  $B_{ON}$ : 18.9 mT at room temperature
- typical  $B_{OFF}$ : 17.3 mT at room temperature
- operates with static magnetic fields and dynamic magnetic fields up to 12 kHz
- typical temperature coefficient of magnetic switching points is  $-1200$  ppm/K at room temperature

### Applications

The HAL 1506 is the optimal sensor for applications with one magnetic polarity, such as:

- clutch pedal position
- wiper position
- door lock
- trunk lock



**Fig. 4–7:** Definition of magnetic switching points for the HAL 1506

**Magnetic Characteristics** at  $T_J = -40\text{ °C}$  to  $+170\text{ °C}$ ,  $V_{DD} = 2.7\text{ V}$  to  $24\text{ V}$ ,  
 Typical Characteristics for  $V_{DD} = 12\text{ V}$

Magnetic flux density values of switching points:

Positive flux density values refer to the magnetic south pole at the top side of the package.

Parameter $T_J$	On point $B_{ON}$			Off point $B_{OFF}$			Hysteresis $B_{HYS}$			Unit
	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	
-40 °C	16.5	20.8	24.8	14	18.9	22.5	-	1.9	-	mT
25 °C	15.4	18.9	22.6	13.8	17.3	21	-	1.6	-	mT
170 °C	13	17	19.5	11.8	15.8	18.2	-	1.2	-	mT

The hysteresis is the difference between the switching points |  $B_{HYS} = B_{ON} - B_{OFF}$  |

**Note** Regarding switching points, temperature coefficients, and B-field switching frequency, customized derivatives via mask option are possible. For more information contact Micronas.

### 4.13.HAL 1507 Magnetic Characteristics

The HAL 1507 unipolar Hall-switch provides low sensitivity (see Fig. 4–8 on page 30).

The output turns low with the magnetic south pole on the top side of the package and turns high if the magnetic field is removed. The sensor does not respond to the magnetic north pole on the top side of the package.

For correct functioning in the application, the sensor requires only the magnetic south pole on the top side of the package.

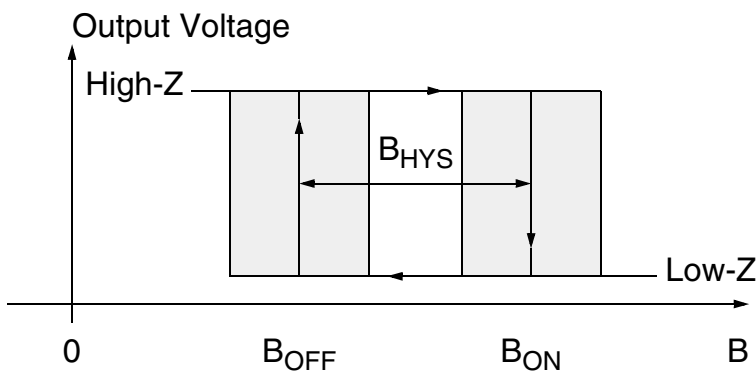
#### Magnetic Features:

- switching type: unipolar
- low sensitivity
- typical  $B_{ON}$ : 28.2 mT at room temperature
- typical  $B_{OFF}$ : 23.9 mT at room temperature
- operates with static magnetic fields and dynamic magnetic fields up to 12 kHz
- typical temperature coefficient of magnetic switching points is  $-300$  ppm/K at room temperature

#### Applications

The HAL 1507 is the optimal sensor for applications with one magnetic polarity and strong magnetic fields at the sensor position, such as:

- gear position detection
- rooftop open/close
- sliding door



**Fig. 4–8:** Definition of magnetic switching points for the HAL 1507

**Magnetic Characteristics** at  $T_J = -40\text{ °C}$  to  $+170\text{ °C}$ ,  $V_{DD} = 2.7\text{ V}$  to  $24\text{ V}$ ,  
 Typical Characteristics for  $V_{DD} = 12\text{ V}$

Magnetic flux density values of switching points:

Positive flux density values refer to the magnetic south pole at the top side of the package.

Parameter $T_J$	On point $B_{ON}$			Off point $B_{OFF}$			Hysteresis $B_{HYS}$			Unit
	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	
-40 °C	24	29.5	35	18.7	24.7	30.7	–	4.8	–	mT
25 °C	23.7	28.2	32.7	19	23.9	28.8	–	4.3	–	mT
170 °C	22.5	27.7	32.9	18.6	23.9	29.2	–	3.8	–	mT

The hysteresis is the difference between the switching points |  $B_{HYS} = B_{ON} - B_{OFF}$  |

**Note** Regarding switching points, temperature coefficients, and B-field switching frequency, customized derivatives via mask option are possible. For more information contact Micronas.

#### 4.14.HAL 1508 Magnetic Characteristics

The HAL 1508 a high-sensitive unipolar switch sensor only sensitive to the magnetic north polarity (see Fig. 4–9 on page 32).

The output turns low with the magnetic north pole on the top side of the package and turns high if the magnetic field is removed. The sensor does not respond to the magnetic south pole.

For correct functioning in the application, the sensor requires only the magnetic north pole on the top side of the package.

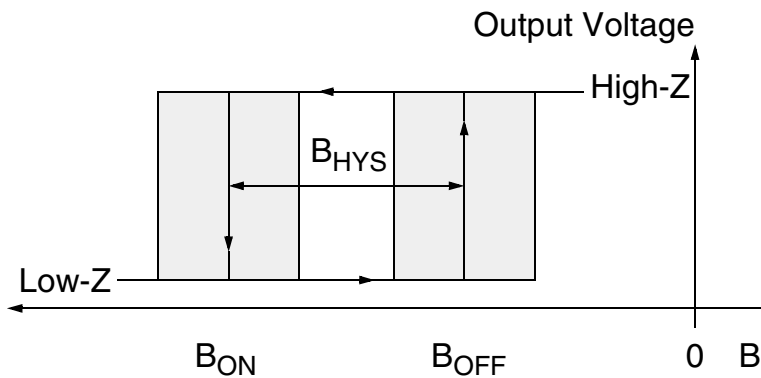
##### **Magnetic Features:**

- switching type: unipolar
- high sensitivity
- typical  $B_{ON}$ :  $-5.5$  mT at room temperature
- typical  $B_{OFF}$ :  $-3.7$  mT at room temperature
- operates with static magnetic fields and dynamic magnetic fields up to 12 kHz
- typical temperature coefficient of magnetic switching points is  $-1000$  ppm/K at room temperature

##### **Applications**

The HAL 1508 is the optimal sensor for all applications with one magnetic polarity and weak magnetic amplitude at the sensor position. In combination with HAL 1503 it is often used for clutch pedal position detection, for instance. Other examples are:

- electric parking brake
- wiper position
- door lock



**Fig. 4–9:** Definition of magnetic switching points for the HAL 150y

**Magnetic Characteristics** at  $T_J = -40\text{ °C}$  to  $+170\text{ °C}$ ,  $V_{DD} = 2.7\text{ V}$  to  $24\text{ V}$ ,  
 Typical Characteristics for  $V_{DD} = 12\text{ V}$

Magnetic flux density values of switching points:

Positive flux density values refer to the magnetic south pole at the top side of the package.

Parameter $T_J$	On point $B_{ON}$			Off point $B_{OFF}$			Hysteresis $B_{HYS}$			Unit
	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	
-40 °C	-7.6	-6.1	-4.4	-5.7	-4	-2.4	-	2.1	-	mT
25 °C	-7.1	-5.5	-3.8	-5.5	-3.7	-2.1	-	1.8	-	mT
170 °C	-6.7	-5	-3	-5.5	-3.6	-1.8	-	1.4	-	mT

The hysteresis is the difference between the switching points |  $B_{HYS} = B_{ON} - B_{OFF}$  |

**Note** Regarding switching points, temperature coefficients, and B-field switching frequency, customized derivatives via mask option are possible. For more information contact Micronas.



### 4.15.HAL 1509 Magnetic Characteristics

The HAL 1509 unipolar inverted Hall-switch provides high sensitivity (see Fig. 4–10 on page 34).

The output turns high with the magnetic south pole on the top side of the package and turns low if the magnetic field is removed. The sensor does not respond to the magnetic north pole on the top side of the package.

For correct functioning in the application, the sensor requires only the magnetic south pole on the top side of the package.

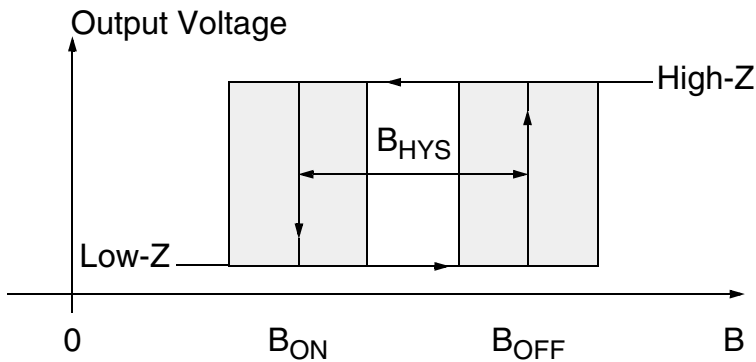
#### Magnetic Features:

- switching type: unipolar inverted
- high sensitivity
- typical  $B_{ON}$ : 3.7 mT at room temperature
- typical  $B_{OFF}$ : 5.5 mT at room temperature
- operates with static magnetic fields and dynamic magnetic fields up to 12 kHz
- typical temperature coefficient of magnetic switching points is  $-1000$  ppm/K at room temperature

#### Applications

The HAL 1509 is the optimal sensor for all applications with one magnetic polarity and weak magnetic amplitude at the sensor position where an inverted output signal is required, such as:

- electric valve actuation
- door lock
- brake position detection



**Fig. 4–10:** Definition of magnetic switching points for the HAL 1509

**Magnetic Characteristics** at  $T_J = -40\text{ °C}$  to  $+170\text{ °C}$ ,  $V_{DD} = 2.7\text{ V}$  to  $24\text{ V}$ ,  
 Typical Characteristics for  $V_{DD} = 12\text{ V}$

Magnetic flux density values of switching points:

Positive flux density values refer to the magnetic south pole at the top side of the package.

Parameter $T_J$	On point $B_{ON}$			Off point $B_{OFF}$			Hysteresis $B_{HYS}$			Unit
	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	
-40 °C	2.4	4	5.7	4.4	6.1	7.6	–	2.1	–	mT
25 °C	2.1	3.7	5.5	3.8	5.5	7.1	–	1.8	–	mT
170 °C	1.8	3.6	5.5	3	5	6.7	–	1.4	–	mT

The hysteresis is the difference between the switching points |  $B_{HYS} = B_{ON} - B_{OFF}$  |

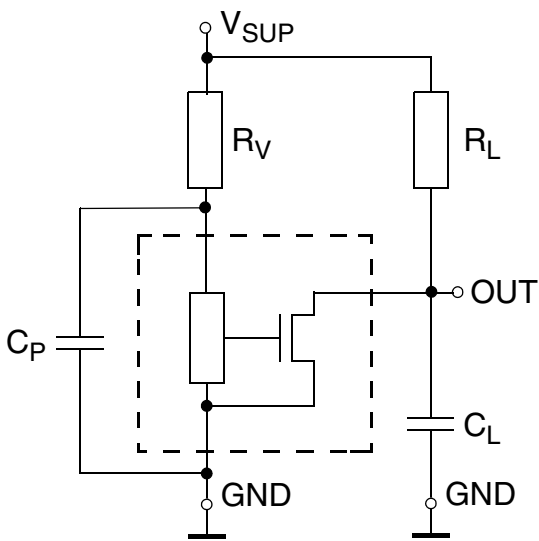
**Note** Regarding switching points, temperature coefficients, and B-field switching frequency, customized derivatives via mask option are possible. For more information contact Micronas.

## 5. Application Notes

### 5.1. Application Circuits

For applications with disturbances on the supply line or radiated disturbances, a series resistor  $R_V$  and two capacitors  $C_P$  and  $C_L$  all placed close to the sensor are recommended (see Fig. 5–1).

For example:  $R_V = 100 \Omega$ ,  $C_P = 10 \text{ nF}$ , and  $C_L = 4.7 \text{ nF}$ .

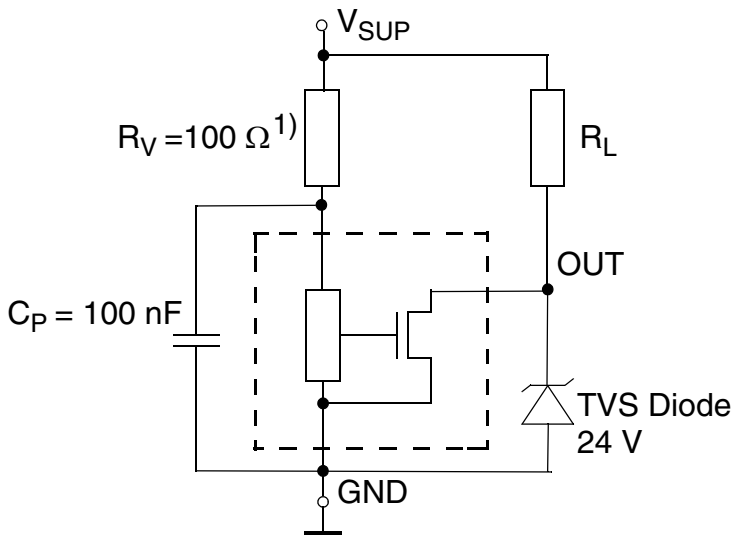


**Fig. 5–1:** Example for a recommended application circuit

$R_L$  is the open-drain pull-up resistor and has to be placed close to the input of the host controller to enable wire-break detection.

### 5.1.1. ESD System Level Application Circuit (ISO10605-2008)

For an ESD system level application circuit according to ISO10605-2008 a 100 nF capacitor at VSUP and an additional TVS diode at OUT are necessary.



<sup>1)</sup> required for 40 V load dump capability

**Fig. 5–2:** Application circuit with external resistor

## 5.2. Ambient Temperature

Due to the internal power dissipation, the temperature on the silicon chip (junction temperature  $T_J$ ) is higher than the temperature outside the package (ambient temperature  $T_A$ ).

$$T_J = T_A + \Delta T$$

Under static conditions and continuous operation, the following equation applies:

$$\Delta T = (I_{SUP} \times V_{SUP} \times R_{thja}) + (I_{OUT} \times V_{OUT} \times R_{thja})$$

For all sensors, the junction temperature range  $T_J$  is specified. The maximum ambient temperature  $T_{Amax}$  can be calculated as:

$$T_{Amax} = T_{Jmax} - \Delta T$$

For typical values, use the typical parameters. For worst case calculation, use the max. parameters for  $I_{SUP}$ ,  $I_{OUT}$ , and  $R_{thja}$ , and the max. value for  $V_{OUT}$  and  $V_{SUP}$  from the application.

### 5.3. Start-Up Behavior

The sensors have an initialization time (enable time  $t_{en}$ ) after applying the supply voltage. The parameter  $t_{en}$  is specified in the Electrical Characteristics (see page 19).

During the initialization time, the output state is defined as High-Z.

After  $t_{en}$ , the output will be Low-Z if the applied magnetic field  $B$  is above  $B_{ON}$ . The output will be High-Z if  $B$  is below  $B_{OFF}$ . In case of sensors with an inverted switching behavior, the output state will be high if  $B > B_{OFF}$  and low if  $B < B_{ON}$ .

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**Note** For non-inverting ICs and magnetic fields between  $B_{OFF}$  and  $B_{ON}$  after applying  $V_{SUP}$ , the output state of the device will be High-Z.

For inverting and north-pole sensitive ICs and magnetic fields between  $B_{OFF}$  and  $B_{ON}$  after applying  $V_{SUP}$ , the output state of the device will be Low-Z.

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For further information see Application Notes for HAL 15xy.

### 5.4. EMC and ESD

For applications with disturbances on the supply line or radiated disturbances, a series resistor and a capacitor are recommended. The series resistor and the capacitor should be placed as close as possible to the HAL sensor.

Special application arrangements were evaluated to pass EMC tests according to different standards, such as ISO 7637, ISO 16750, IEC 61967, ISO 11452 and ISO 62132.

## 6. Data Sheet History

1. Data Sheet: "HAL 150y, Hall-Effect Switch with Open-Drain Output (3-wire) in SOT23 Package", March 23, 2016; DSH000179\_001EN. First release of the Data Sheet.
2. Data Sheet: "HAL 150y, Hall-Effect Switch with Open-Drain Output (3-wire) in SOT23 Package", June 15, 2016; DSH000179\_002EN. Second release of the Data Sheet.

Major changes:

- ESD and Latch-up: Values updated
- ESD System Level Application Circuit (ISO10605-2008) added